

# DEC

## SBP1535 THRU SBP1560

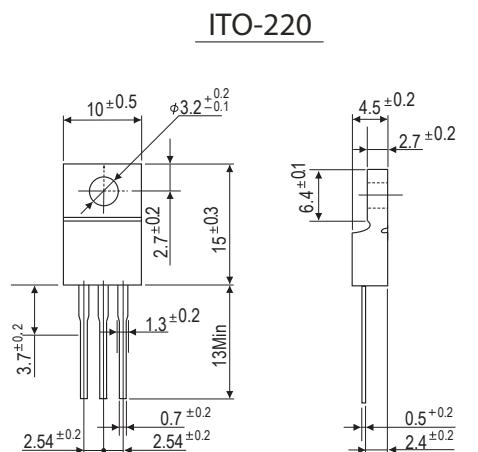
CURRENT 15.0Amperes  
VOLTAGE 35 to 60 Volts

### Features

- Plastic Package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss, high efficiency
- High current capability, Low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Dual rectifier construction
- High temperature soldering guaranteed : 250 °C/10 seconds, 0.25" (6.35mm) from case

### Mechanical Data

- Case : JEDEC ITO-220 molded plastic body
- Terminals : Lead solderable per MIL-STD-750, Method 2026
- Polarity : As marked. No suffix indicates Common Cathode, suffix "A" indicates Common Anode
- Mounting Position : Any
- Weight : 0.08 ounce, 2.24 grams



Dimensions in inches and (millimeters)

### Maximum Ratings and Electrical Characteristics

(Ratings at 25 °C ambient temperature unless otherwise specified, single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%)

	Symbols	SBP1535	SBP1545	SBP1550	SBP1560	Units
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	35	45	50	60	Volts
Maximum RMS voltage	V <sub>RMS</sub>	25	32	35	42	Volts
Maximum DC blocking voltage	V <sub>DC</sub>	35	45	50	60	Volts
Maximum average forward rectified current at T <sub>c</sub> =105 °C per diode/device	I <sub>(AV)</sub>			7.5 15.0		Amps Amps
Repetitive peak forward current(square wavr, 20KHZ) at T <sub>c</sub> =105 °C per diode	I <sub>FRM</sub>			15.0		Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I <sub>FSM</sub>			150.0		Amps
Maximum instantaneous forward voltage at 7.5A (Note 1)	V <sub>F</sub>		0.65		0.75	Volts
Maximum instantaneous reverse current at rated DC blocking voltage (Note1)	T <sub>A</sub> =25 °C	I <sub>R</sub>		1.0		mA
	T <sub>A</sub> =125 °C		15		50	
Typical thermal resistance (Note 2)	R <sub>θJC</sub>			2.5		°C/W
Operating junction temperature range	T <sub>J</sub>			-65 to +150		°C
Storage temperature range	T <sub>STG</sub>			-65 to +175		°C

#### Notes:

- (1) Pulse test: 300μS pulse width, 1% duty cycle
- (2) Thermal resistance from junction to case

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## RATINGS AND CHARACTERISTIC CURVES SBP1535 THRU SBP1560

FIG.1-FORWARD CURRENT DERATING CURVE

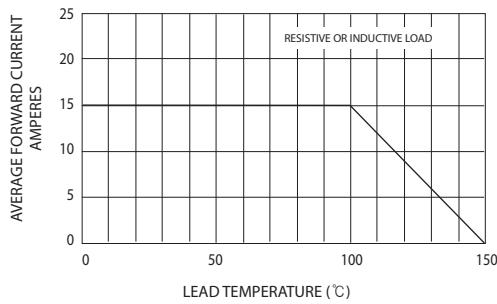


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

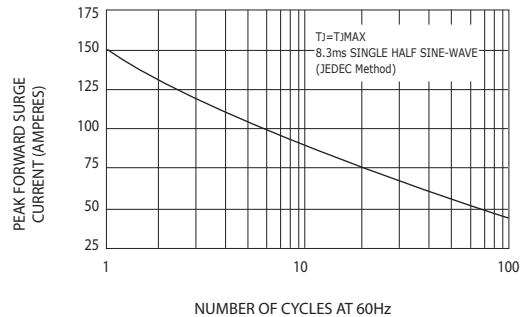


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

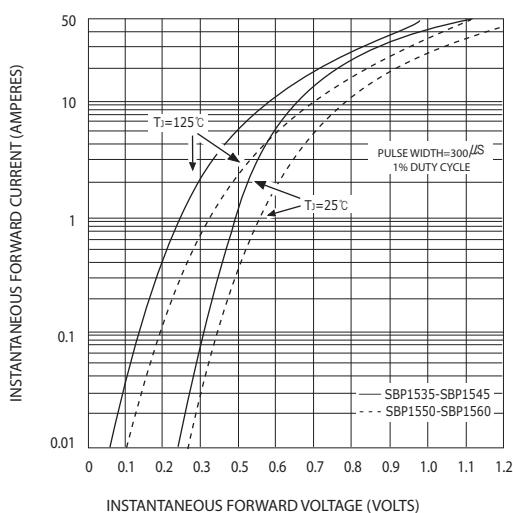


FIG.4-TYPICAL REVERSE CHARACTERISTICS

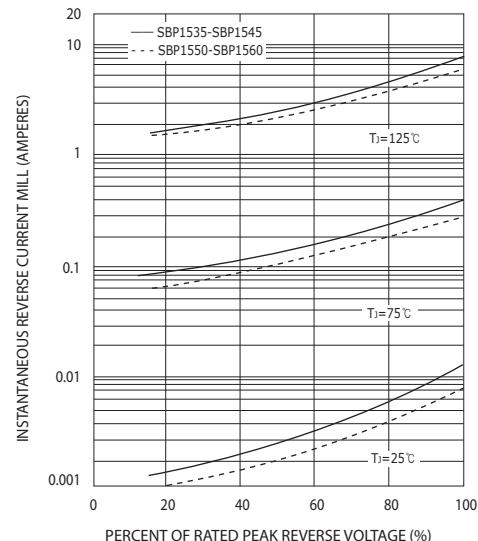


FIG.5-TYPICAL JUNCTION CAPACITANCE

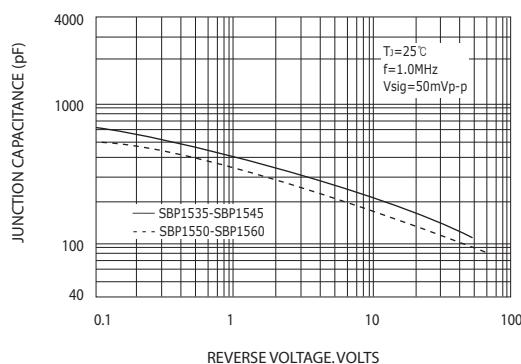


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

